

MGBR20V300C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

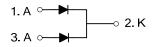
DESCRIPTION

The UTC **MGBR20V300C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

FEATURES

* Low forward voltage drop * High switching speed

SYMBOL



TO-220 TO-220F

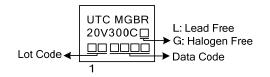
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing	
Lead Free	Halogen Free	Fackage	1	2	3	i acking	
MGBR20V300CL-TA3-T	MGBR20V300CG-TA3-T	TO-220	А	К	А	Tube	
MGBR20V300CL-TF3-T	MGBR20V300CG-TF3-T	TO-220F	А	К	А	Tube	
MGBR20V300CL-TQ2-T	MGBR20V300CG-TQ2-T	TO-263	А	К	А	Tube	
MGBR20V300CL-TQ2-R	MGBR20V300CG-TQ2-R	TO-263	А	К	А	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode

MGBR20V300CL-TA3-T	(1) T: Tube, R: Tape Reel
(2)Package Type	(2) TA3: TO-220, TF3: TO-220F, TQ2: TO-263
(3)Green Package	(3) L: Lead Free, G: Halogen Free and Lead Free

MARKING



Preliminary

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by	ZU%.			
PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V _{RM}	300	V
Working Peak Reverse Voltage		V _{RWM}	300	V
Peak Repetitive Reverse Voltage		V _{RRM}	300	V
Average Rectified Output Current Per	Per Leg		10	А
Device	Total	I _O	20	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	180	А
Operating Junction Temperature		TJ	-65 ~ +150	°C
Storage Temperature		T _{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER		SYMBOL	RATINGS	UNIT
	TO-220		2	
Typical Thermal Resistance	TO-220F	$\theta_{\rm JC}$	4	°C/W
	TO-263		3	

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A=25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage	V _{(BR)R}	I _R =0.50mA	300			V
Forward Voltage Drop	VEM	I _F =10A, TJ=25°C			0.87	V
		I _F =10A, TJ=125°C			0.74	V
Leakage Current	RM	V _R =300V, T _J =25°C			100	μA
		V _R =300V, T _J =125°C			30	mA

Notes: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Device mounted on additional heatsink 2 inch × 2 inch AI board.



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